

ATTACHMENT A: SEARCH HISTORY

L Number	Hits	Search Text	DB	Time stamp
1	52	(data with writing) and method and semiconductor and memory and device and (first same block) and rewrit\$3 and (second same block) and adjoin\$3	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/09 09:40
2	1687	(data with writing) and method and semiconductor and memory and device and (first same block) and rewrit\$3 and (second same block)	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/09 09:40
3	784	((data with writing) and method and semiconductor and memory and device and (first same block) and rewrit\$3 and (second same block)) and (first same cell) and (second same cell)	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/09 09:41
4	220	((((data with writing) and method and semiconductor and memory and device and (first same block) and rewrit\$3 and (second same block)) and (first same cell) and (second same cell)) and (verify\$3 same data))	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/09 09:41
5	198	(((((data with writing) and method and semiconductor and memory and device and (first same block) and rewrit\$3 and (second same block)) and (first same cell) and (second same cell)) and (verify\$3 same data)) and (rewrit\$3 same data))	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/09 09:45
7	8	(((((data with writing) and method and semiconductor and memory and device and (first same block) and rewrit\$3 and (second same block)) and (first same cell) and (second same cell)) and (verify\$3 same data)) and (rewrit\$3 same data)) and adjoin\$3	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/09 09:42
8	173	(((((data with writing) and method and semiconductor and memory and device and (first same block) and rewrit\$3 and (second same block)) and (first same cell) and (second same cell)) and (verify\$3 same data)) and (rewrit\$3 same data)) and 365/\$7.cccls.	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/09 09:45
10	1	((((((data with writing) and method and semiconductor and memory and device and (first same block) and rewrit\$3 and (second same block)) and (first same cell) and (second same cell)) and (verify\$3 same data)) and (rewrit\$3 same data)) and 365/\$7.cccls.) and (series or parallel)) and adjoin	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/09 09:45
11	2	((((((data with writing) and method and semiconductor and memory and device and (first same block) and rewrit\$3 and (second same block)) and (first same cell) and (second same cell)) and (verify\$3 same data)) and (rewrit\$3 same data)) and 365/\$7.cccls.) and (series or parallel)) and adjoin\$3	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/09 09:45
9	161	((((((data with writing) and method and semiconductor and memory and device and (first same block) and rewrit\$3 and (second same block)) and (first same cell) and (second same cell)) and (verify\$3 same data)) and (rewrit\$3 same data)) and 365/\$7.cccls.) and (series or parallel))	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/09 09:48